BCX19

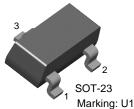


SEMICONDUCTOR®

BCX19

NPN Medium Power Transistor

- This device is designed for general purpose amplifiers.
- Sourced from process 38.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings $T_{C}=25^{\circ}C$ unless otherwise noted

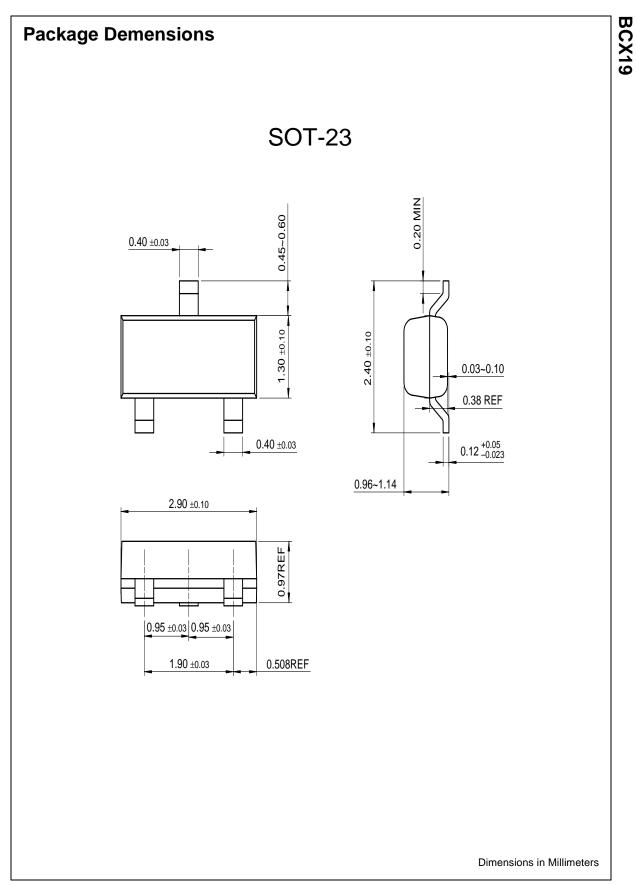
| Symbol | Parameter | | Value | Units | |
|-----------------------------------|----------------------------------|--------------|------------|-------|--|
| V _{CEO} | Collector-Emitter Voltage | | 45 | V | |
| V _{CBO} | Collector-Base Voltage | | 50 | V | |
| V _{EBO} | Emitter-Base Voltage | | 5.0 | V | |
| I _C | Collector current | - Continuous | 500 | mW | |
| T _J , T _{stg} | Junction and Storage Temperature | | -55 ~ +150 | °C | |

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|----------------------|--------------------------------------|--|-----------------|------|------------|----------|
| OFF CHARA | ACTERISTICS | | | | | |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | $I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$ | 45 | | | V |
| V _{(BR)CES} | Collector-Emitter Breakdown Voltage | $I_{\rm C} = 10 \mu {\rm A}, I_{\rm C} = 0$ | 50 | | | V |
| I _{CBO} | Collector Cutoff Current | $V_{CB} = 20V, I_E = 0$ $V_{CB} = 20V, I_E = 0, T_A = 150^{\circ}C$ | | | 100 5.0 | nA μA |
| I _{EBO} | Emitter Cutoff Current | $V_{EB} = 5.0V, I_{C} = 0$ | | | 10 | μΑ |
| ON CHARA | CTERISTICS | | | • | • | |
| h _{FE} | DC Current Gain | $ I_{C} = 100 m A, V_{CE} = 1.0 V \\ I_{C} = 300 m A, V_{CE} = 1.0 V \\ I_{C} = 500 m A, V_{CE} = 1.0 V $ | 100 70 40 | | 600 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 500mA, I _B = 50mA | | | 0.62 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 500mA, V _{CE} = 1.0V | | | 1.2 | V |

Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Max. | Units |
|----------------|---|------------|-------------|
| PD | Total Device Dissipation Derate above 25°C | 300 2.4 | mW mW/°C |
| | | | |
| R_{\thetaJA} | Thermal Resistance, Junction to Ambient | 417 | °C/W |



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|--------------------------|---------------------------|---|
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